

Electrical Characteristics ($T_A=25^\circ\text{C}$)

	Symbol	Min.	Typ.	Max..	Unit	Condition
GaAs Emitter (per channel)						
Forward Voltage	V_F		1.25	1.5	V	$I_F=20 \text{ mA}$
Reverse Current	I_R		0.1	10	μA	$V_R=3.0 \text{ V}$
Capacitance	C_O		25		pF	$V_R=0 \text{ V}$
Detector (per channel)						
Collector-Emitter Breakdown Voltage	BV_{CEO}	30/55			V	$I_C=100 \mu\text{A}$
Collector-Emitter Leakage Current	I_{CEO}		1.0	100	nA	$V_{CE}=10 \text{ V}, I_F=0$
Collector-Emitter Capacitance	C_{CE}		3.4		pF	$V_{CE}=10 \text{ V}, f=1 \text{ MHz}$
Package						
Current Transfer Ratio IL/D/Q30/55 IL/D/Q31	CTR	100 200	400 400		%	$I_F=10 \text{ mA}, V_{CE}=5 \text{ V}$ $I_F=10 \text{ mA}, V_{CE}=5 \text{ V}$
Collector-Emitter Saturation Voltage	V_{CESat}		0.9	1.0	V	$I_C=50 \text{ mA}, I_F=50 \text{ mA}$
Isolation Test Voltage		5300			VAC _{RM} S	
Isolation Resistance	R_{ISOL}		10^{12}		W	
Coupling Capacitance	C_{ISOL}		0.5		pF	
Rise Time	t_R		10		μs	$V_{CC}=13.5 \text{ V}, I_F=50 \text{ mA}, R_L=100 \Omega$
Fall Time	t_F		35		μs	

Figure 1. Forward voltage versus forward current

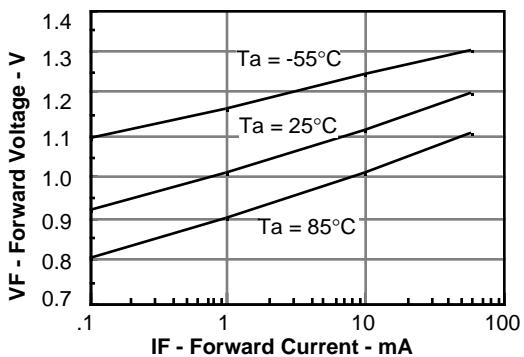


Figure 2. Normalized non-saturated and saturated CTR_{ce} at $T_A=25^\circ\text{C}$ versus LED current

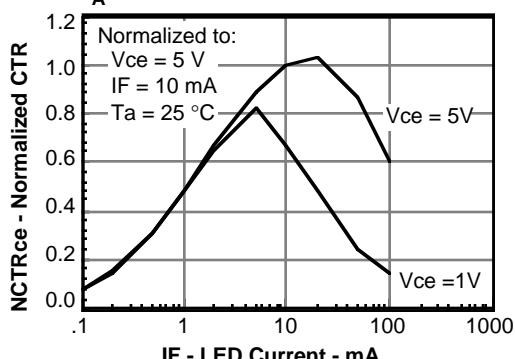


Figure 3. Normalized non-saturated and saturated collector-emitter current versus LED current

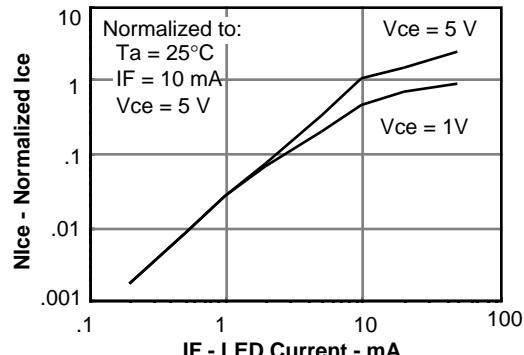


Figure 4. Normalized collector-base photocurrent versus LED current

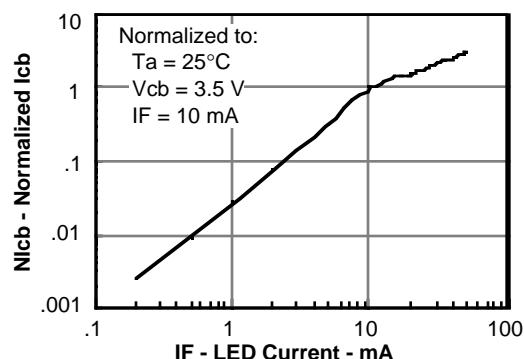


Figure 5. Hfe current gain versus base current

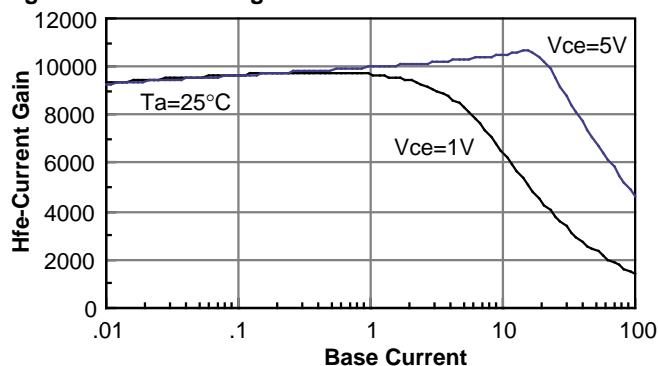


Figure 6. Low to high propagation delay versus collector load resistance and LED current

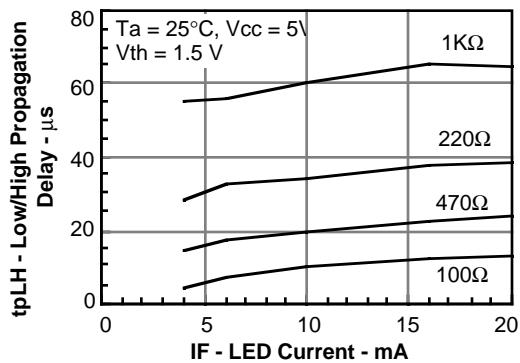


Figure 7. High to low propagation delay versus collector load resistance and LED current

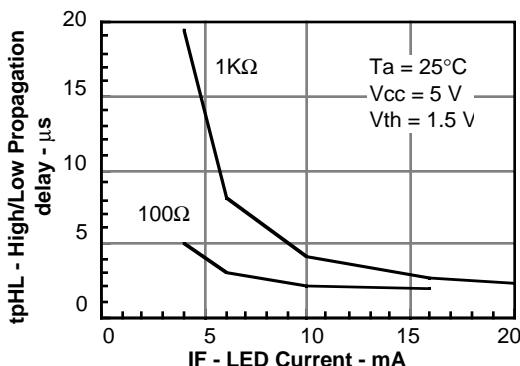


Figure 8. Switching waveforms

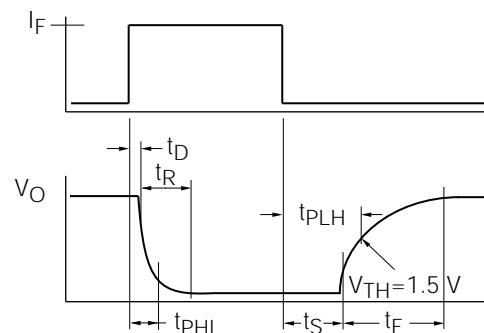


Figure 9. Switching schematic

